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## HD1750FX

### HIGH VOLTAGE NPN POWER TRANSISTOR FOR HIGH DEFINITION AND NEW SUPER-SLIM CRT DISPLAYS

- STATE-OF-THE-ART TECHNOLOGY: DIFFUSED COLLECTOR "ENHANCED GENERATION" EHVS1
- WIDER RANGE OF OPTIMUM DRIVE CONDITIONS
- LESS SENSITIVE TO OPERATING TEMPERATURE VARIATION
- FULLY INSULATED POWER PACKAGE U.L. COMPLIANT

#### APPLICATIONS

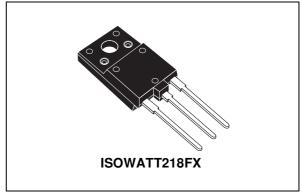
 HORIZONTAL DEFLECTION OUTPUT FOR DIGITAL TV, HDTV AND HIGH-END MONITORS

#### DESCRIPTION

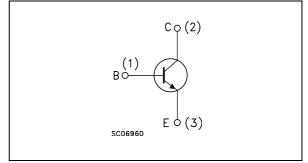
The device is manufactured using Diffused Collector in Planar technology adopting "Enhance High Voltage Structure" (EHVS1) developed to fit High-Definition CRT displays.

The new HD product series show improved silicon efficiency bringing updated performance to the Horizontal Deflection stage.

#### Figure 1: Package



#### Figure 2: Internal Schematic Diagram



#### Table 1: Order Codes

| Part Number | Marking  | Package      | Packaging |
|-------------|----------|--------------|-----------|
| HD1750FX    | HD1750FX | ISOWATT218FX | TUBE      |

#### HD1750FX

| Symbol  | Parameter                                       | Value      | Unit |
|---|---|------------|------|
| V <sub>CES</sub>  | Collector-Emitter Voltage (V <sub>BE</sub> = 0) | 1700       | V    |
| V <sub>CEO</sub>  | Collector-Emitter Voltage (I <sub>B</sub> = 0)  | 800        | V    |
| $V_{EBO}$   | Emitter-Base Voltage (I <sub>C</sub> = 0)       | 10         | V    |
| ۱ <sub>C</sub>  | Collector Current                               | 24         | А    |
| I <sub>CM</sub>   | Collector Peak Current (t <sub>p</sub> < 5ms)   | 36         | А    |
| I <sub>B</sub>  | Base Current                                    | 12         | Α    |
| I <sub>BM</sub>   | Base Peak Current (t <sub>p</sub> < 5ms)        | 18         | А    |
| P <sub>tot</sub>  | Total Dissipation at $T_{C} = 25 \ ^{\circ}C$   | 75         | W    |
| V <sub>ins</sub> Insulation Withstand Voltage (RMS) from All Three Leads to External Heatsink |   | 2500       | V    |
| T <sub>stg</sub>  | Storage Temperature                             | -65 to 150 | °C   |
| ТJ  | Max. Operating Junction Temperature             | 150        | °C   |

#### **Table 2: Absolute Maximum Ratings**

#### **Table 3: Thermal Data**

| R <sub>thj-case</sub> | Thermal Resistance Junction-Case | Max | 1.67 | °C/W |
|-----------------------|----------------------------------|-----|------|------|
|-----------------------|----------------------------------|-----|------|------|

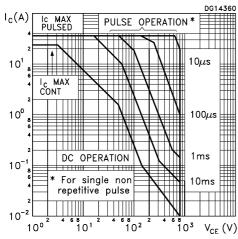
### Table 4: Electrical Characteristics ( $T_{case}$ = 25 °C unless otherwise specified)

| Symbol                  | Parameter                               | Test Co                       | nditions                            | Min. | Тур. | Max. | Unit |
|-------------------------|---|-------------------------------|-------------------------------------|------|------|------|------|
| I <sub>CES</sub>        | Collector Cut-off Current               | V <sub>CE</sub> = 1700 V      |                                     |      |      | 0.2  | mA   |
|                         | (V <sub>BE</sub> = 0)                   | V <sub>CE</sub> = 1700 V      | T <sub>C</sub> = 125 <sup>o</sup> C |      |      | 2    | mA   |
| I <sub>EBO</sub>        | Emitter Cut-off Current                 | V <sub>EB</sub> = 5 V         |                                     |      |      | 10   | μA   |
|                         | $(I_{\rm C} = 0)$                       |                               |                                     |      |      |      |      |
| V <sub>CEO(sus)</sub> * | Collector-Emitter<br>Sustaining Voltage | I <sub>C</sub> = 10 mA        |                                     | 800  |      |      | V    |
|                         | $(I_{B} = 0)$                           |                               |                                     |      |      |      |      |
| V <sub>EBO</sub>        | Emitter-Base Voltage                    | I <sub>E</sub> = 10 mA        |                                     | 10   |      |      | V    |
|                         | $(I_{\rm C}=0)$                         |                               |                                     |      |      |      |      |
| V <sub>CE(sat)</sub> *  | Collector-Emitter<br>Saturation Voltage | I <sub>C</sub> = 12 A         | I <sub>B</sub> = 3 A                |      |      | 3    | V    |
| V <sub>BE(sat)</sub> *  | Base-Emitter Saturation<br>Voltage      | I <sub>C</sub> = 12 A         | I <sub>B</sub> = 3 A                |      | 0.95 | 1.5  | V    |
| h <sub>FE</sub>         | DC Current Gain                         | I <sub>C</sub> = 1 A          | V <sub>CE</sub> = 5 V               |      | 30   |      |      |
|                         |   | I <sub>C</sub> = 12 A         | $V_{CE} = 5 V$                      | 6.5  |      | 9.5  |      |
|                         | INDUCTIVE LOAD                          | I <sub>C</sub> = 12 A         | f <sub>h</sub> = 31250 Hz           |      |      |      |      |
| t <sub>s</sub>          | Storage Time                            | I <sub>B(on)</sub> = 1.9 A    | I <sub>B(off)</sub> = -8.1 A        |      | 3.1  | 3.8  | μs   |
| t <sub>f</sub>          | Fall Time                               | V <sub>CE(fly)</sub> = 1320 V | $V_{BE(off)} = -2.7 V$              |      | 350  | 500  | ns   |
|                         |   | $L_{BB(off)} = 0.8 \ \mu H$   | 22(0)                               |      |      |      |      |
|                         | INDUCTIVE LOAD                          | I <sub>C</sub> = 6.5 A        | f <sub>h</sub> = 100 kHz            |      |      |      |      |
| t <sub>s</sub>          | Storage Time                            | I <sub>B(on)</sub> = 1.2 A    | I <sub>B(off)</sub> = -5.85 A       |      | 1.7  | 2    | μs   |
| t <sub>f</sub>          | Fall Time                               | $V_{CE(fly)} = 1220 V$        | $V_{BE(off)} = -2.7 V$              |      | 180  | 250  | ns   |
|                         |   | $L_{BB(off)} = 0.25 \ \mu H$  |                                     |      |      |      |      |

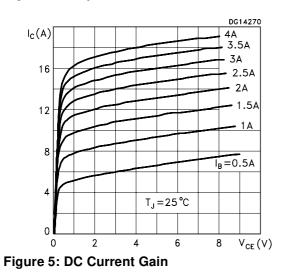
\* Pulsed: Pulsed duration = 300  $\mu$ s, duty cycle  $\leq$  1.5 %.



Figure 3: Safe Operating Area



**Figure 4: Output Chatacterisctics** 



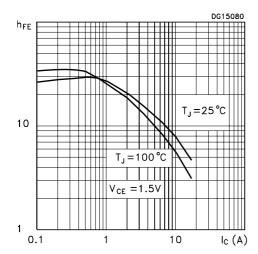


Figure 6: Derating Curve

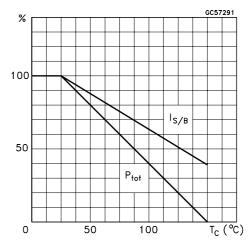
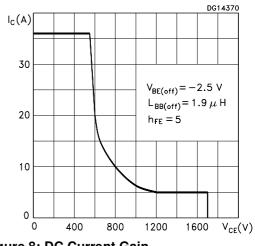
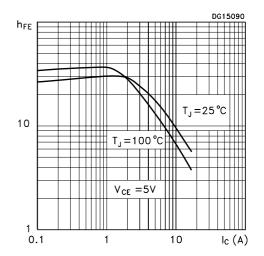


Figure 7: Reverse Biased SOA







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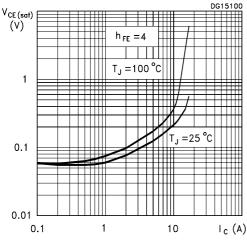


Figure 9: Collector-Emitter Saturation Voltage

Figure 10: Power Losses

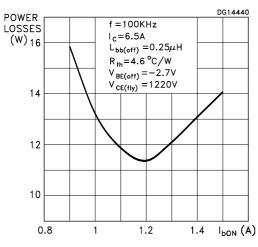


Figure 11: Inductive Load Switching Time

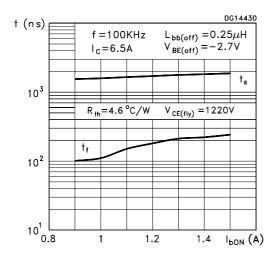
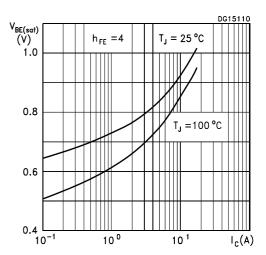


Figure 12: Base-Emitter Saturation Voltage





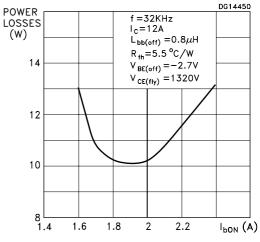
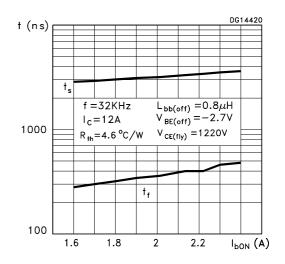


Figure 14: Inductive Load Switching Time



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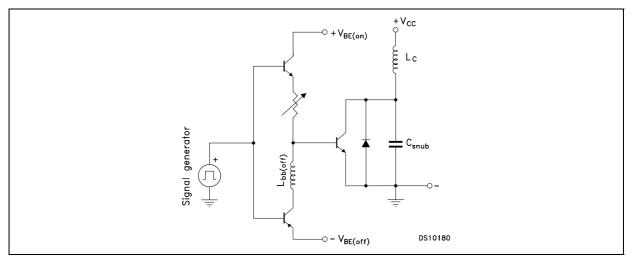
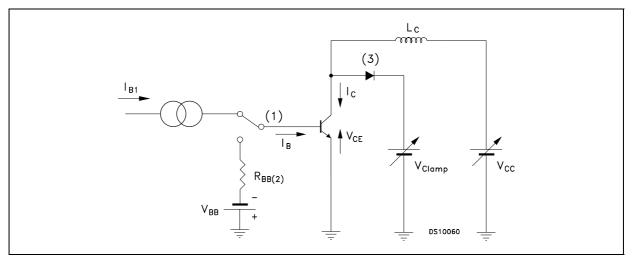


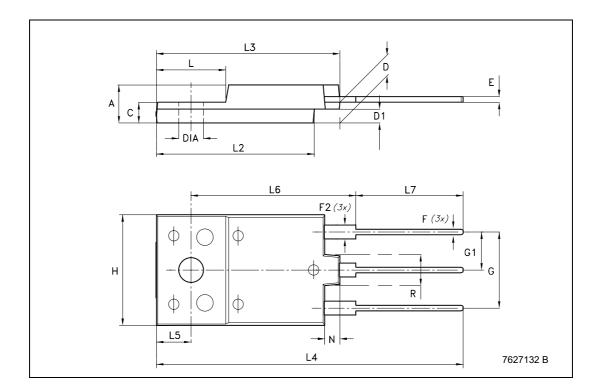
Figure 15: Power Losses and Inductive Load Switching Test Circuit





#### ISOWATT218FX MECHANICAL DATA

| DIM. | mm.   |      |       |  |  |
|------|-------|------|-------|--|--|
|      | MIN.  | ТҮР  | MAX.  |  |  |
| A    | 5.30  |      | 5.70  |  |  |
| С    | 2.80  |      | 3.20  |  |  |
| D    | 3.10  |      | 3.50  |  |  |
| D1   | 1.80  |      | 2.20  |  |  |
| E    | 0.80  |      | 1.10  |  |  |
| F    | 0.65  |      | 0.95  |  |  |
| F2   | 1.80  |      | 2.20  |  |  |
| G    | 10.30 |      | 11.50 |  |  |
| G1   |       | 5.45 |       |  |  |
| Н    | 15.30 |      | 15.70 |  |  |
| L    | 9     |      | 10.20 |  |  |
| L2   | 22.80 |      | 23.20 |  |  |
| L3   | 26.30 |      | 26.70 |  |  |
| L4   | 43.20 |      | 44.40 |  |  |
| L5   | 4.30  |      | 4.70  |  |  |
| L6   | 24.30 |      | 24.70 |  |  |
| L7   | 14.60 |      | 15    |  |  |
| Ν    | 1.80  |      | 2.20  |  |  |
| R    | 3.80  |      | 4.20  |  |  |
| Dia  | 3.40  |      | 3.80  |  |  |





#### Figure 5: Revision History

| Release Date | Version | Change Designator                    |
|--------------|---------|--------------------------------------|
| 30-May-2005  | 1       | Initial Release.                     |
| 19-Dec-2005  | 2       | New h <sub>FE</sub> value in table 4 |



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